NB2869A

Low Power, Reduced EMI Clock Synthesizer

The NB2869A is a versatile spread spectrum frequency modulator designed specifically for a wide range of clock frequencies. The NB2869A reduces ElectroMagnetic Interference (EMI) at the clock source, allowing system wide reduction of EMI of all clock dependent signals. The NB2869A allows significant system cost savings by reducing the number of circuit board layers, ferrite beads and shielding that are traditionally required to pass EMI regulations.

The NB2869A uses the most efficient and optimized modulation profile approved by the FCC and is implemented by using a proprietary all digital method.

The NB2869A modulates the output of a single PLL in order to "spread" the bandwidth of a synthesized clock, and more importantly, decreases the peak amplitudes of its harmonics. This results in significantly lower system EMI compared to the typical narrow band signal produced by oscillators and most frequency generators. Lowering EMI by increasing a signal's bandwidth is called 'spread spectrum clock generation'.

The NB2869A is targeted towards all portable devices with very low power requirements like MP3 players and digital still cameras.

Features

- Generates an EMI Optimized Clocking Signal at the Output
- Integrated Loop Filter Components
- Operates with a 3.3 V / 2.5 V Supply
- Operating Current less than 4.0 mA
- Low Power CMOS Design
- Input Frequency Range: 6.0 MHz to 12 MHz for 2.5 V
  Input Frequency Range: 6.0 MHz to 13 MHz for 3.3 V
- Generates a 1X Low EMI Spread Spectrum clock of the Input Frequency
- Frequency Deviation ±1% @ 10 MHz
- Available in TSOP-6 Package (TSOT-23-6)
- Pb-Free Package is Available

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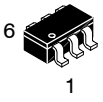
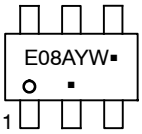
http://onsemi.com

MARKING DIAGRAM*



TSOP-6
(TSOT-23-6)
SN SUFFIX
CASE 318G



E08 = Specific Device Code
A = Assembly Location
Y = Year
W = Work Week
▪ = Pb-Free Package

(Note: Microdot may be in either location)

*For additional marking information, refer to Application Note AND8002/D.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

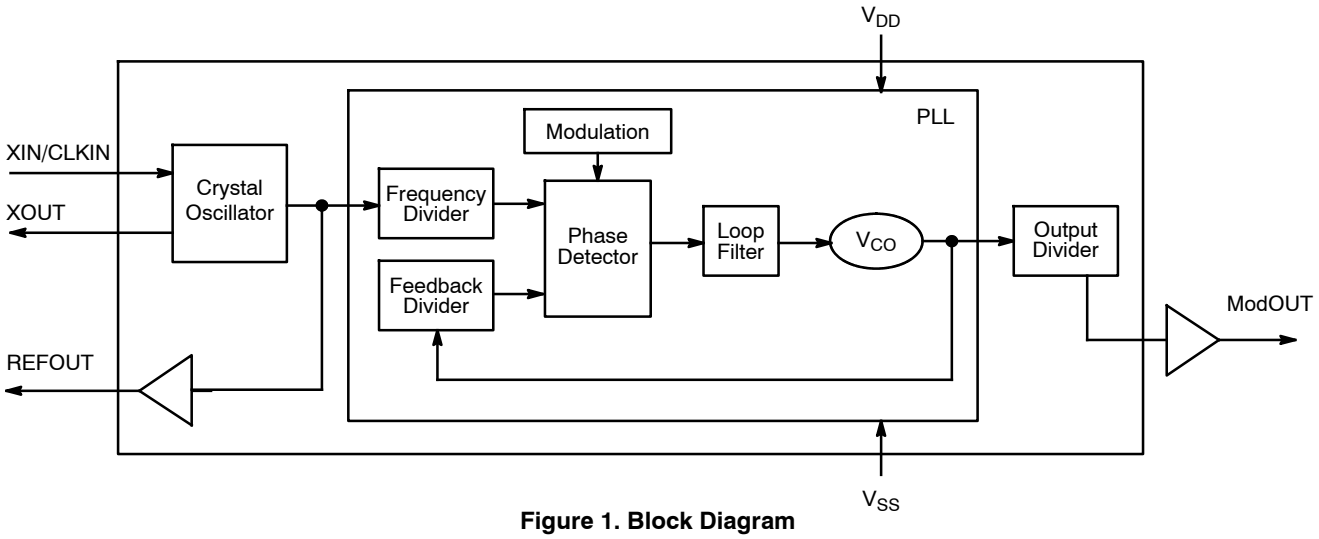


Figure 1. Block Diagram

Table 1. KEY SPECIFICATIONS

Description		Specification
Supply Voltages		V_{DD} = 3.3 V / 2.5 V
Frequency Range	For 2.5 V Supply For 3.3 V Supply	6 MHz < CLKIN < 12 MHz 6 MHz < CLKIN < 13 MHz
Cycle−to−Cycle Jitter		200 ps (maximum)
Output Duty Cycle		45/55% (worst case)
Modulation Rate Equation		FIN/256
Frequency Deviation		±1% @ 10 MHz

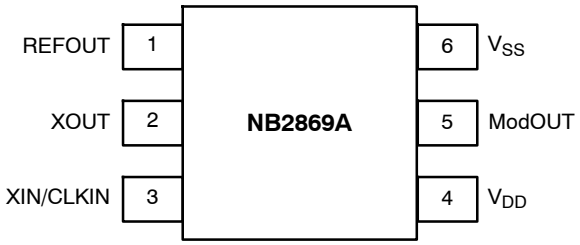


Figure 2. Pin Configuration

Table 2. PIN DESCRIPTION

Pin #	Pin Name	Type	Description
1	REFOUT	O	Buffered output of the input frequency.
2	XOUT	O	Crystal connection. If using an external reference, this pin must be left unconnected.
3	XIN/CLKIN	I	Crystal connection or external reference frequency input. This pin has dual functions. It can be connected either to an external crystal or an external reference clock
4	V_{DD}	P	Power supply for the entire chip.
5	ModOUT	O	Spread spectrum clock output.
6	V_{SS}	P	Ground connection.

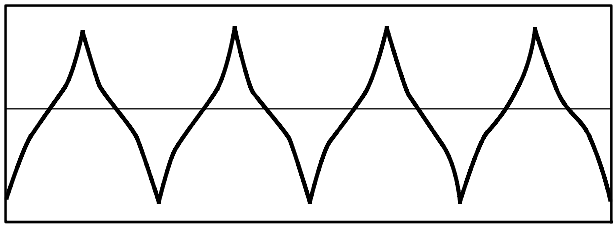


Figure 3. Modulation Profile

Table 3. MAXIMUM RATINGS

Symbol	Description	Rating	Unit
V_{DD}, V_{IN}	Voltage on any pin with respect to Ground	0.5 to + 7.0	V
T_{STG}	Storage Temperature	−65 to +125	°C
T_A	Operating Temperature	0 to 70	°C
T_s	Max. Soldering Temperature (10 sec)	260	°C
T_J	Junction Temperature	150	°C
T_{DV}	Static Discharge Voltage (As per MIL−STD−883, Method 3015)	2	kV

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Table 4. DC ELECTRICAL CHARACTERISTICS FOR 2.5 V SUPPLY (Test Conditions: All parameters are measured at room temperature 25°C)

Symbol	Description	Min	Typ	Max	Unit
V_{IL}	Input LOW Voltage	GND - 0.3		0.8	V
V_{IH}	Input HIGH Voltage	2.0		V_{DD} + 0.3	V
I_{IL}	Input LOW Current			-35	μA
I_{IH}	Input HIGH Current			35	μA
I_{XOL}	XOUT Output LOW Current (@ 0.5 V, V_{DD} = 2.5 V)		3.0		mA
I_{XOH}	XOUT Output HIGH Current (@ 2.5 V, V_{DD} = 2.5 V)		3.0		mA
V_{OL}	Output LOW Voltage (V_{DD} = 2.5 V, I_{OL} = 8.0 mA)			0.6	V
V_{OH}	Output HIGH Voltage (V_{DD} = 2.5 V, I_{OH} = 8.0 mA)	1.8			V
I_{DD}	Static Supply Current (Note 1)		1.0		mA
I_{CC}	Dynamic Supply Current (2.5 V, 10 MHz, and No Load)		3.0		mA
V_{DD}	Operating Voltage	2.375	2.5	2.625	V
t_{ON}	Powerup Time (first locked cycle after powerup) (Note 2)			5.0	mS
Z_{OUT}	Clock Output Impedance		50		Ω

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

1. XIN/CLKIN pin is pulled low.
2. V_{DD} and XIN/CLKIN input are stable.

Table 5. AC ELECTRICAL CHARACTERISTICS FOR 2.5 V SUPPLY

Symbol	Description	Min	Typ	Max	Unit
CLKIN	Input Frequency	6.0		12	MHz
ModOUT	Output Frequency	6.0		12	MHz
f_d	Frequency Deviation Input Frequency = 6.0 MHz Input Frequency = 12 MHz			±1.6 ±0.78	%
t_{LH} (Note 3)	Output Rise Time (measured at 0.7 V to 1.7 V)		1.5	1.7	ns
t_{HL} (Note 3)	Output Fall Time (measured at 1.7 V to 0.7 V)	0.5	1.0	1.2	ns
t_{JC}	Jitter (Cycle-to-Cycle)			200	ps
t_D	Output Duty Cycle	45	50	55	%

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

3. t_{LH} and t_{HL} are measured at capacitive load of 15 pF.

Table 6. DC ELECTRICAL CHARACTERISTICS FOR 3.3 V SUPPLY (Test Conditions: All parameters are measured at room temperature 25°C)

Symbol	Description	Min	Typ	Max	Unit
V_{IL}	Input LOW Voltage	GND − 0.3		0.8	V
V_{IH}	Input HIGH Voltage	2.0		V_{DD} + 0.3	V
I_{IL}	Input LOW Current			−35	μA
I_{IH}	Input HIGH Current			35	μA
I_{XOL}	XOUT Output LOW Current (@ 0.4 V, V_{DD} = 3.3 V)		3.0		mA
I_{XOH}	XOUT Output HIGH Current (@ 2.5 V, V_{DD} = 3.3 V)		3.0		mA
V_{OL}	Output LOW Voltage (V_{DD} = 3.3 V, I_{OL} = 8.0 mA)			0.4	V
V_{OH}	Output HIGH Voltage (V_{DD} = 3.3 V, I_{OH} = 8.0 mA)	2.5			V
I_{DD}	Static Supply Current (Note 4)		1.3		mA
I_{CC}	Dynamic Supply Current (3.3 V, 10 MHz, and No Load)		4.0		mA
V_{DD}	Operating Voltage	2.7	3.3	3.6	V
t_{ON}	Powerup Time (first locked cycle after powerup) (Note 5)			5.0	mS
Z_{OUT}	Clock Output Impedance		45		Ω

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

4. XIN/CLKIN pin is pulled low.
5. V_{DD} and XIN/CLKIN input are stable.

Table 7. AC ELECTRICAL CHARACTERISTICS FOR 3.3 V SUPPLY

Symbol	Description	Min	Typ	Max	Unit
CLKIN	Input Frequency	6.0		13	MHz
ModOUT	Output Frequency	6.0		13	MHz
f_d	Frequency Deviation Input Frequency = 6.0 MHz Input Frequency = 13 MHz			±1.6 ±0.77	%
t_{LH} (Note 6)	Output Rise Time (measured at 0.8 V to 2.0 V)	0.5	1.4	1.6	ns
t_{HL} (Note 6)	Output Fall Time (measured at 2.0 V to 0.8 V)	0.4	1.0	1.2	ns
t_{JC}	Jitter (Cycle−to−Cycle)			200	ps
t_D	Output Duty Cycle	45	50	55	%

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

6. t_{LH} and t_{HL} are measured at capacitive load of 15 pF.

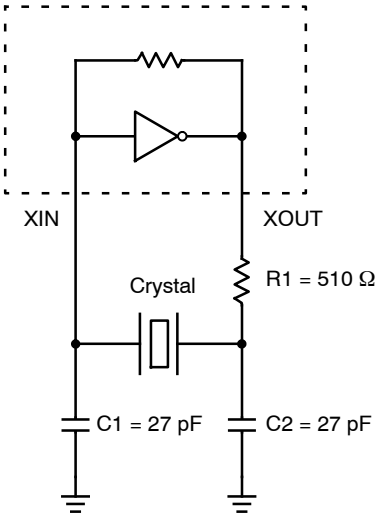


Figure 4. Typical Crystal Oscillator Circuit

Table 8. TYPICAL CRYSTAL SPECIFICATIONS

Fundamental AT Cut Parallel Resonant Crystal	
Nominal Frequency	8.0 MHz
Frequency Tolerance	±50 ppm or better at 25°C
Operating Temperature Range	−25°C to +85°C
Storage Temperature	−40°C to +85°C
Load Capacitance	18 pF
Shunt Capacitance	7 pF Maximum
ESR	25 Ω

ORDERING INFORMATION

Device	Marking	Temperature Range	Package	Shipping†	Availability
NB2869ASNR2	E08	0°C – 70°C	TSOP−6 (TSOT−23−6)	2500 Tape & Reel	*Now*
NB2869ASNR2G	E08	0°C – 70°C	TSOP−6 (TSOT−23−6) (Pb−Free)	2500 Tape & Reel	*Contact Sales Representative*

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

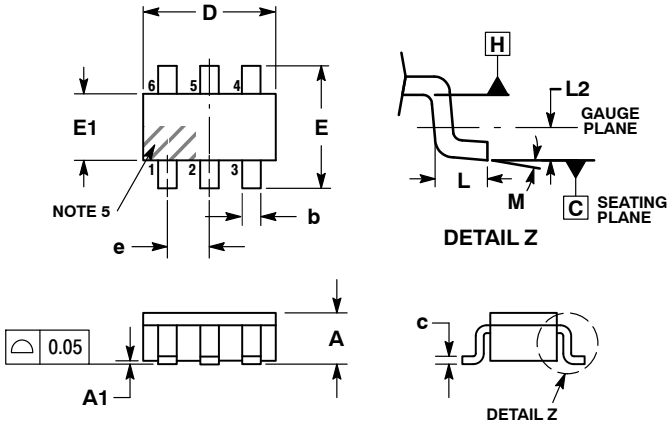
MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

ON Semiconductor®

SCALE 2:1

TSOP−6
CASE 318G−02
ISSUE V

DATE 12 JUN 2012



NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSIONS D AND E1 ARE DETERMINED AT DATUM H.
5. PIN ONE INDICATOR MUST BE LOCATED IN THE INDICATED ZONE.

	MILLIMETERS		
DIM	MIN	NOM	MAX
A	0.90	1.00	1.10
A1	0.01	0.06	0.10
b	0.25	0.38	0.50
c	0.10	0.18	0.26
D	2.90	3.00	3.10
E	2.50	2.75	3.00
E1	1.30	1.50	1.70
e	0.85	0.95	1.05
L	0.20	0.40	0.60
L2	0.25 BSC		
M	0°	–	10°

STYLE 1:
PIN 1. DRAIN
2. DRAIN
3. GATE
4. SOURCE
5. DRAIN
6. DRAIN

STYLE 2:
PIN 1. EMITTER 2
2. BASE 1
3. COLLECTOR 1
4. EMITTER 1
5. BASE 2
6. COLLECTOR 2

STYLE 3:
PIN 1. ENABLE
2. N/C
3. R BOOST
4. Vz
5. V in
6. V out

STYLE 4:
PIN 1. N/C
2. V in
3. NOT USED
4. GROUND
5. ENABLE
6. LOAD

STYLE 5:
PIN 1. EMITTER 2
2. BASE 2
3. COLLECTOR 1
4. EMITTER 1
5. BASE 1
6. COLLECTOR 2

STYLE 6:
PIN 1. COLLECTOR
2. COLLECTOR
3. BASE
4. EMITTER
5. COLLECTOR
6. COLLECTOR

STYLE 7:
PIN 1. COLLECTOR
2. COLLECTOR
3. BASE
4. N/C
5. COLLECTOR
6. EMITTER

STYLE 8:
PIN 1. Vbus
2. D(in)
3. D(in)+
4. D(out)+
5. D(out)
6. GND

STYLE 9:
PIN 1. LOW VOLTAGE GATE
2. DRAIN
3. SOURCE
4. DRAIN
5. DRAIN
6. HIGH VOLTAGE GATE

STYLE 10:
PIN 1. D(OUT)+
2. GND
3. D(OUT)−
4. D(IN)−
5. VBUS
6. D(IN)+

STYLE 11:
PIN 1. SOURCE 1
2. DRAIN 2
3. DRAIN 2
4. SOURCE 2
5. GATE 1
6. DRAIN 1/GATE 2

STYLE 12:
PIN 1. I/O
2. GROUND
3. I/O
4. I/O
5. VCC
6. I/O

STYLE 13:
PIN 1. GATE 1
2. SOURCE 2
3. GATE 2
4. DRAIN 2
5. SOURCE 1
6. DRAIN 1

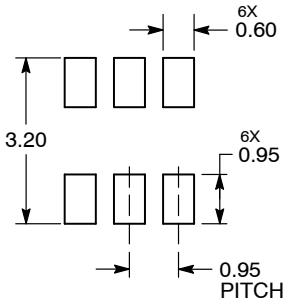
STYLE 14:
PIN 1. ANODE
2. SOURCE
3. GATE
4. CATHODE/DRAIN
5. CATHODE/DRAIN
6. CATHODE/DRAIN

STYLE 15:
PIN 1. ANODE
2. SOURCE
3. GATE
4. DRAIN
5. N/C
6. CATHODE

STYLE 16:
PIN 1. ANODE/CATHODE
2. BASE
3. EMITTER
4. COLLECTOR
5. ANODE
6. CATHODE

STYLE 17:
PIN 1. EMITTER
2. BASE
3. ANODE/CATHODE
4. ANODE
5. CATHODE
6. COLLECTOR

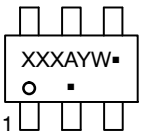
RECOMMENDED SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



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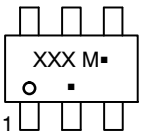

STANDARD

XXX = Specific Device Code
A = Assembly Location
Y = Year
W = Work Week
▪ = Pb−Free Package

XXX = Specific Device Code
M = Date Code
▪ = Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present.

DOCUMENT NUMBER:	**98ASB14888C**	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped “CONTROLLED COPY” in red.
DESCRIPTION:	**TSOP−6**	**PAGE 1 OF 1**

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Email Requests to: orderlit@onsemi.com

onsemi Website: www.onsemi.com

TECHNICAL SUPPORT
North American Technical Support:
Voice Mail: 1 800−282−9855 Toll Free USA/Canada
Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:
Phone: 00421 33 790 2910
For additional information, please contact your local Sales Representative

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